TOSHIBA Field Effect Transistor Silicon P-Channel MOS Type (U-MOS IV)

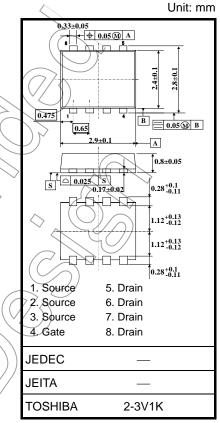
TPCP8102

Notebook PC Applications Portable Equipment Applications

- Small footprint due to small and thin package
- Low drain-source ON-resistance: R_{DS} (ON) = 13.5 m Ω (typ.)
- High forward transfer admittance: $|Y_{fs}| = 24 \text{ S} (typ.)$
- Low leakage current: $I_{DSS} = -10 \ \mu A \ (max) \ (V_{DS} = -20 \ V)$
- Enhancement model: V_{th} = -0.45 to -1.2 V (V_{DS} = -10 V, I_D = -200 µA)

Absolute Maximum Ratings (Ta = 25°C)

Characteristic			Symbol	Rating	Unit
Drain-source voltage			V _{DSS}	-20	V
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)			V _{DGR}	-20	V
Gate-source voltage			V _{GSS}	± 12	√ v
Drain current	DC (Note 1)	Ι _D	-7.2	
	Pulse (Note 1)	I _{DP}	-28,8	A
Drain power dissipation (t = 5 s) (Note 2a)			PD	1.68	W
Drain power dissipation (t = 5 s) (Note 2b)			PD	0.84	w
Single-pulse avalanche energy (Note 3)			((E _{AS})	33.7	mJ
Avalanche current			IAR	-7.2	A
Repetitive avalanche energy (Note 4)			FAR	0.168	mJ
Channel temperature			T _{ch}	(150/	°C
Storage temperature range			∠ T _{stg}	-55~150	°C



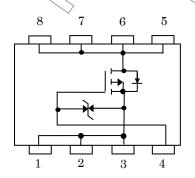
Weight: 0.017 g (typ.)

Note: For Notes 1 to 5, refer to the next page.

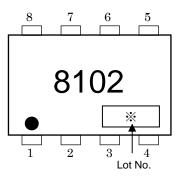
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

This transistor is an electrostatic-sensitive device. Handle with care.

Circuit Configuration



Marking (Note 5)

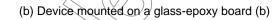


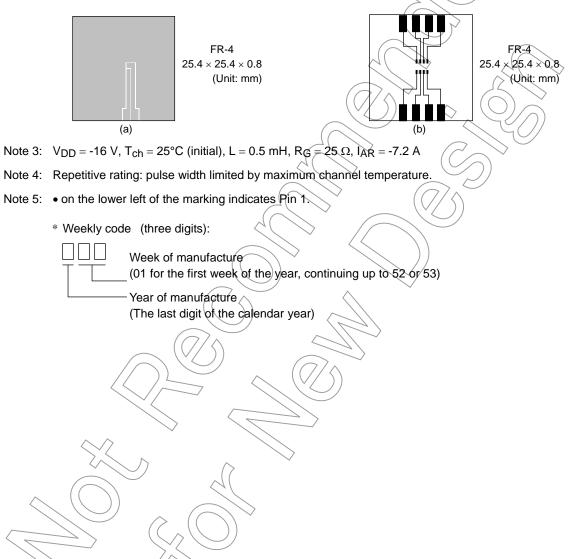
Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient $(t = 5 s)$ (Note 2a)	R _{th (ch-a)}	74.4	°C/W
Thermal resistance, channel to ambient (t = 5 s) (Note 2b)	R _{th (ch-a)}	148.8	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C during use of the device.

Note 2: (a) Device mounted on a glass-epoxy board (a)





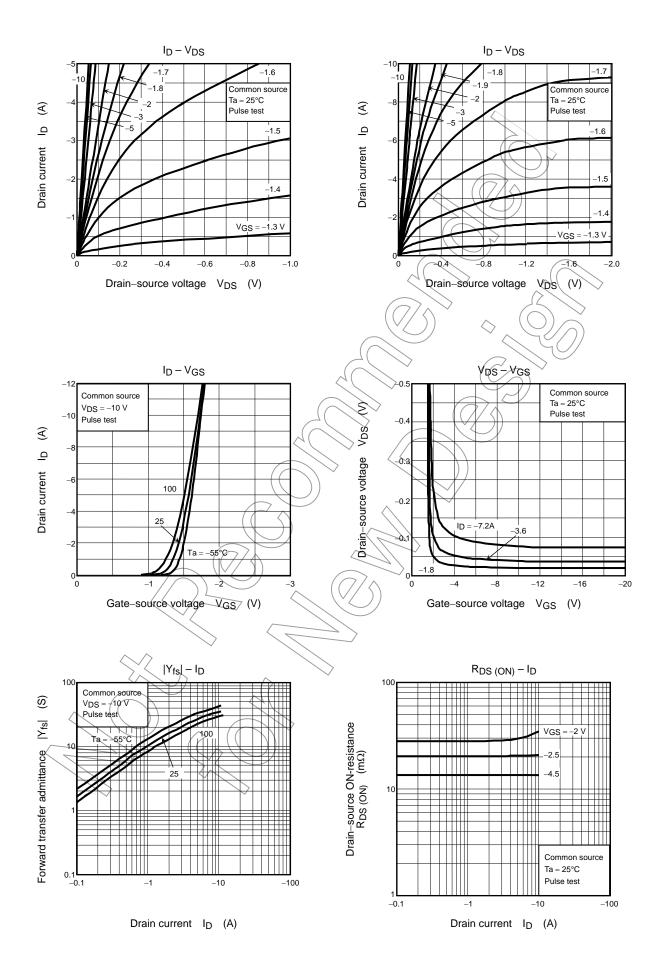
Electrical Characteristics (Ta = 25°C)

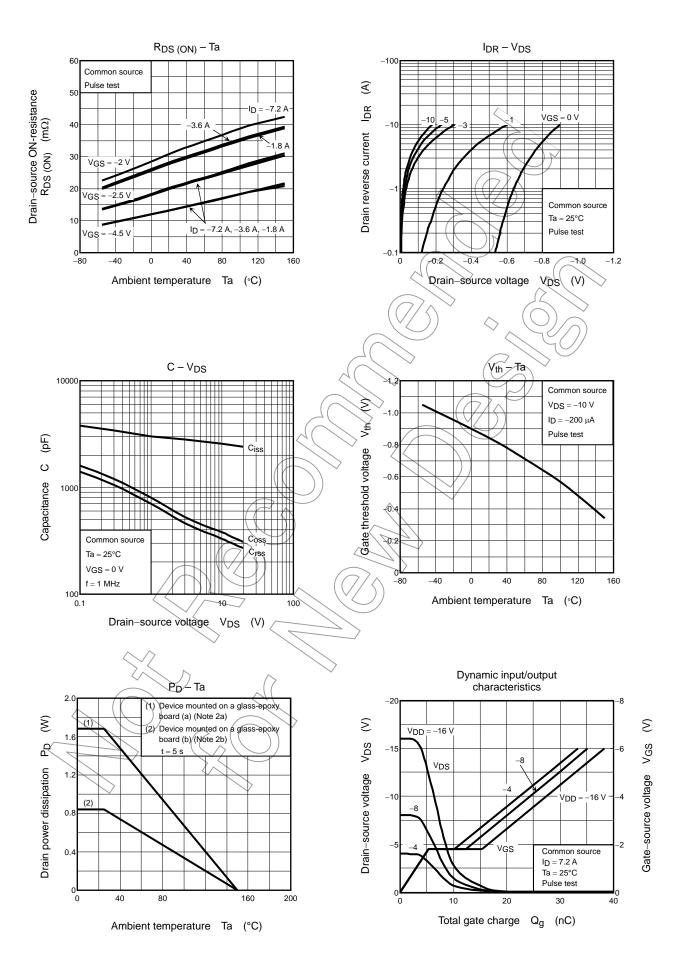
Characteristic		Symbol	Test Condition	Min	Тур.	Мах	Unit
Gate leakage current		I _{GSS}	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0 \text{ V}$	_	—	±10	μΑ
Drain cutoff curre	ent	I _{DSS}	$V_{DS} = -20 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	_	—	-10	μΑ
Drain-source breakdown voltage		V (BR) DSS	$I_{D} = -10 \text{ mA}, V_{GS} = 0 \text{ V}$	-20	—	—	V
	akuown voltage	V (BR) DSX	$I_D = -10 \text{ mA}, V_{GS} = 12 \text{ V}$	-8		_	v
Gate threshold ve	oltage	V _{th}	V_{DS} = -10 V, I_D = -200 μ A	-0.45		-1.2	V
Drain-source ON-resistance			$V_{GS} = -2.0 \text{ V}, \text{ I}_{D} = -1.8 \text{ A}$		29	80	mΩ
		R _{DS (ON)}	$V_{GS} = -2.5 \text{ V}, \text{ I}_{D} = -3.6 \text{ A}$	\mathcal{A}	20	30	
			$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -3.6 \text{ A}$		13.5	18	
Forward transfer admittance		Y _{fs}	V _{DS} = -10 V, I _D = -3.6 A	12	24		S
Input capacitance		C _{iss}			2560		
Reverse transfer capacitance		C _{rss}	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		330	\searrow	pF
Output capacitance		C _{oss}	(γ)	-6	380	> -	
Switching time	Rise time	tr	V _{GS} 0 V H _D = -3.6 A	K	5) _	
	Turn-on time	t _{on}			> <u>)</u> 14	_	
	Fall time	t _f			42	_	ns
	Turn-off time	toff	$V_{DD} \simeq -10$ V Duty $\leq 1\%$, t _w = 10 µs	_	142	_	
Total gate charge (gate-source plus gate-drain)		Qg	$V_{DD} \simeq -16 \text{ V}, \text{ V}_{GS} = -5 \text{ V},$		33	_	_
Gate-source charge 1		Qgs1	$I_{\rm D} = -7.2 \rm{A}$		5.4	_	nC
Gate-drain ("Miller") charge		Qgd		_	10	_	

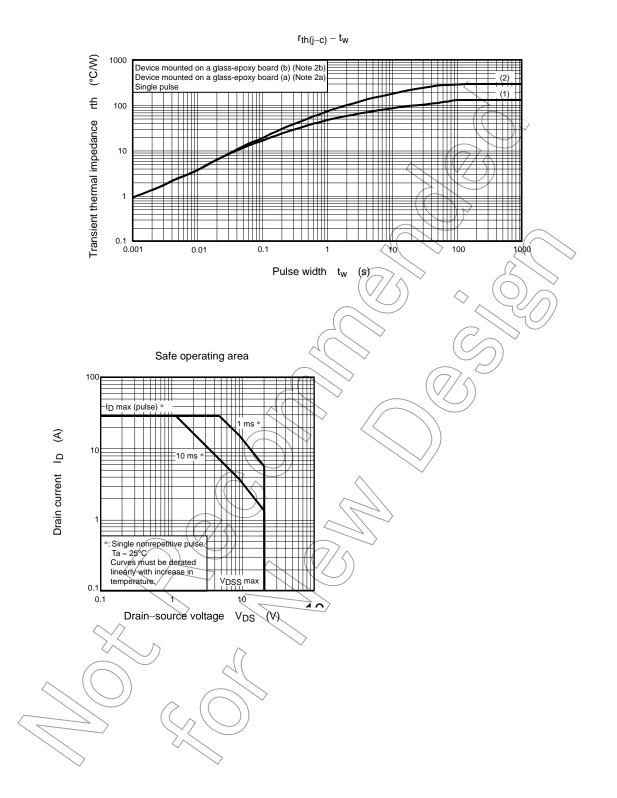
Source-Drain Ratings and Characteristics (Ta = 25°C)

Charac	teristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Drain reverse current	Pulse (Note 1)		-	—	_	-28.8	А
Forward voltage	(diode)	V _{DSF}	I _{DR} = -3.6 A, V _{GS} = 0 V	_	_	1.2	V

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